PNP/NPN Epitaxial Planar Silicon Transistor

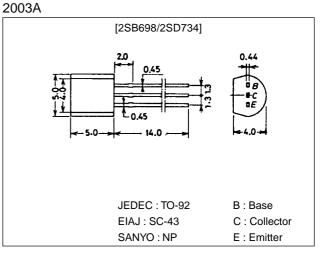


2SB698/2SD734

1W AF Output, Electronic Governor, DC-DC Converter Applications

Package Dimensions

unit:mm



(): 2SB698 for audio 1W output.

Specifications

Absolute Maximum Ratings at Ta = 25°C

| Parameter | Symbol | Conditions | Ratings | Unit |
|------------------------------|------------------|------------|-------------|------|
| Collector-to-Base Voltage | V _{CBO} | | (–)25 | V |
| Collector-to-Emitter Voltage | VCEO | | (–)20 | V |
| Emitter-to-Base Voltage | V _{EBO} | | (–)5 | V |
| Collector Current | ۱ _C | | (-)0.7 | A |
| Collector Current (Pulse) | I _{CP} | | (–)1.5 | A |
| Collector Dissipation | PC | | 0.6 | W |
| Junction Temperature | Tj | | 150 | °C |
| Storage Temperature | Tstg | | -55 to +150 | °C |

Electrical Characteristics at Ta = 25°C

| Parameter | Symbol | Conditions | Ratings | | | Unit |
|--------------------------|-------------------|--|---------|------|--------|------|
| Falameter | | | min | typ | max | Unit |
| Collector Cutoff Current | I _{CBO} | V _{CB} =(-)20V, I _E =0 | | | (–)1.0 | μA |
| Emitter Cutoff Current | IEBO | V _{EB} =(-)4V, I _C =0 | | | (–)1.0 | μA |
| DC Current Gain | h _{FE} 1 | V _{CE} =(-)2V, I _C =(-)50mA | 60* | | 560* | |
| | h _{FE} 2 | V _{CE} =(-)2V, I _C =(-)500mA | 50 | | | |
| Gain-Bandwidth Product | fT | V _{CE} =(-)10V, I _C =(-)50mA | | 250 | | MHz |
| Output Capacitance | Cob | V _{CB} =(-)10V, f=1MHz | | (13) | | pF |
| | | | | 8 | | pF |

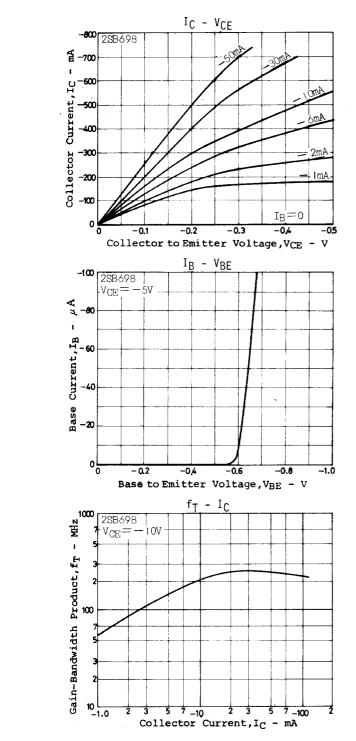
\ast : The 2SB698/2SD734 are classified by 50mA h_{FE} as follows :

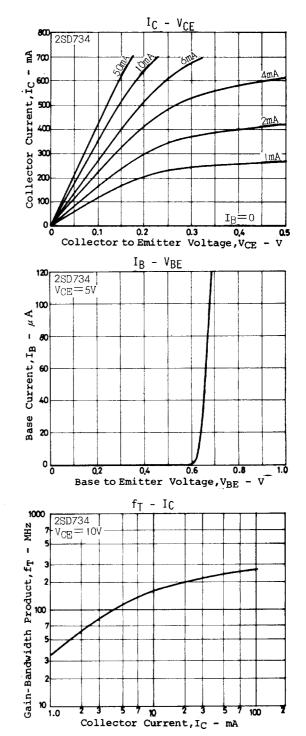
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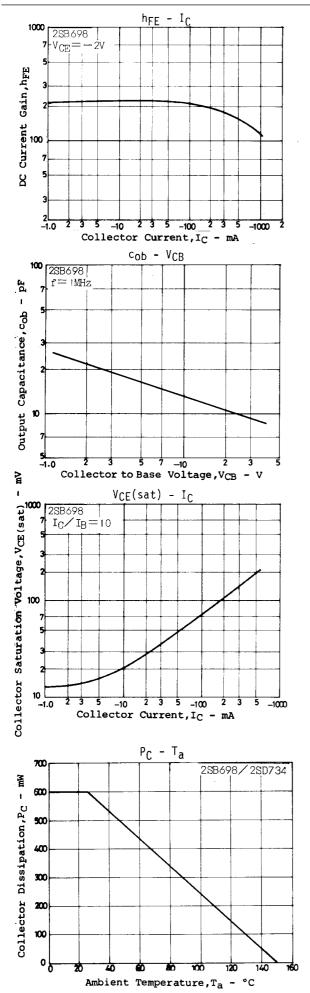
SANYO Electric Co., Ltd. Semiconductor Bussiness Headquaters TOKYO OFFICE Tokyo Bldg., 1-10, 1 Chome, Ueno, Taito-ku, TOKYO, 110-8534 JAPAN

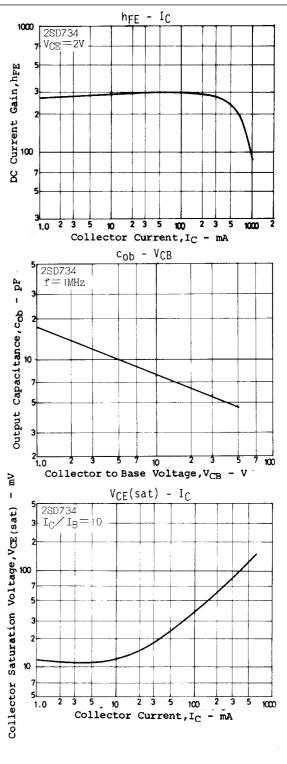
2SB698/2SD734

| Parameter | Symbol | Conditions | Ratings | | | Unit |
|---|----------------------|---|---------|--------|---------|------|
| | | | min | typ | max | Onit |
| Collector-to-Emitter Saturation Voltage | VCE(sat) | I _C =(–)500mA, I _B =(–)50mA | | (-0.2) | (-0.45) | V |
| | | | | 0.13 | 0.3 | V |
| Base-to-Emitter Saturation Voltage | VBE(sat) | I _C =(-)500mA, I _B =(-)50mA | | (–)0.9 | | V |
| Collector-to-Base Breakdown Voltage | V(BR)CBO | I _C =(-)10µA, I _E =0 | (–)25 | | | V |
| Collector-to-Emitter Brakdown Voltage | V(BR)CEO | I _C =(−)1mA, R _{BE} =∞ | (–)20 | | | V |
| Emitter-to-Base Breakdown Voltage | V _{(BR)EBO} | I _E =(-)10μA, I _C =0 | (–)5 | | | V |









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